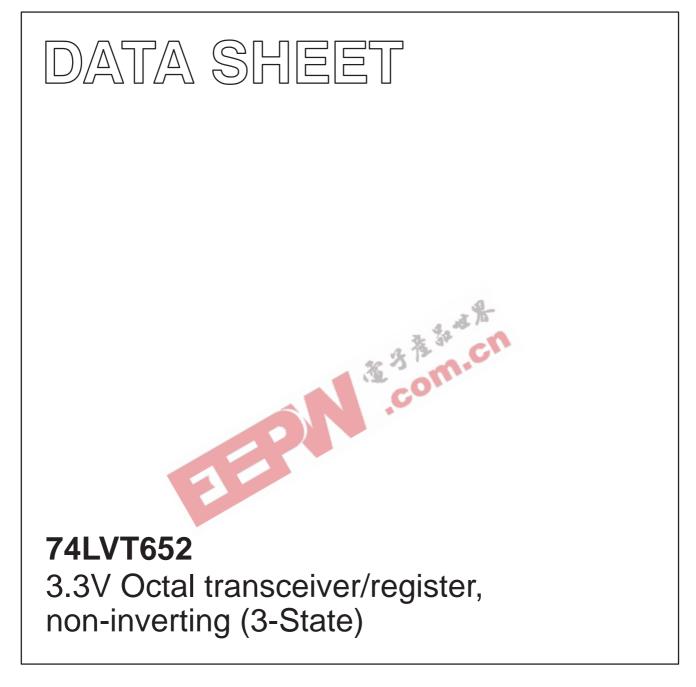
INTEGRATED CIRCUITS



Product specification Supersedes data of 1994 May 20 IC23 Data Handbook 1998 Feb 19



74LVT652

FEATURES

- Independent registers for A and B buses
- Multiplexed real-time and stored data
- 3-State outputs
- Output capability: +64mA/-32mA
- TTL input and output switching levels
- Input and output interface capability to systems at 5V supply
- Bus-hold data inputs eliminate the need for external pull-up resistors to hold unused inputs
- Live insertion/extraction permitted
- No bus current loading when output is tied to 5V bus
- Power-up 3-State
- Power-up reset
- Latch-up protection exceeds 500mA per JEDEC Std 17
- ESD protection exceeds 2000V per MIL STD 883 Method 3015 and 200V per Machine Model

QUICK REFERENCE DATA

DESCRIPTION

The LVT652 is a high-performance BiCMOS product designed for V_{CC} operation at 3.3V.

This device combines low static and dynamic power dissipation with high speed and high output drive.

The 74LVT652 transceiver/register consists of bus transceiver circuits with 3-State outputs, D–type flip-flops, and control circuitry arranged for multiplexed transmission of data directly from the input bus or the internal registers. Data on the A or B bus will be clocked into the registers as the appropriate clock pin goes High. Output Enable (OEAB, OEBA) and Select (SAB, SBA) pins are provided for bus management.

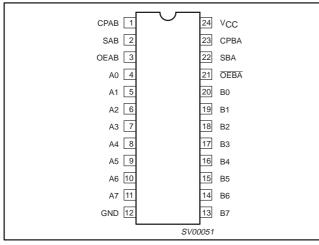


SYMBOL	PARAMETER	CONDITIONS T _{amb} = 25°C; GND = 0V	TYPICAL	UNIT
t _{PLH} t _{PHL}	Propagation delay An to Bn or Bn to An	C _L = 50pF; V _{CC} = 3.3V	2.8 2.6	ns
C _{IN}	Input capacitance	$V_1 = 0V \text{ or } 3V$	4	pF
C _{I/O}	I/O capacitance	Outputs disabled; $V_{I/O} = 0V \text{ or } 3V$	10	pF
I _{CCZ}	Total supply current	Outputs disabled; $V_{CC} = 3.6V$	0.13	mA

ORDERING INFORMATION

PACKAGES	TEMPERATURE RANGE	OUTSIDE NORTH AMERICA	NORTH AMERICA	DWG NUMBER
24-Pin Plastic SOL	-40°C to +85°C	74LVT652 D	74LVT652 D	SOT137-1
24-Pin Plastic SSOP Type II	-40°C to +85°C	74LVT652 DB	74LVT652 DB	SOT340-1
24-Pin Plastic TSSOP Type I	-40°C to +85°C	74LVT652 PW	74LVT652PW DH	SOT355-1

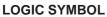
PIN CONFIGURATION

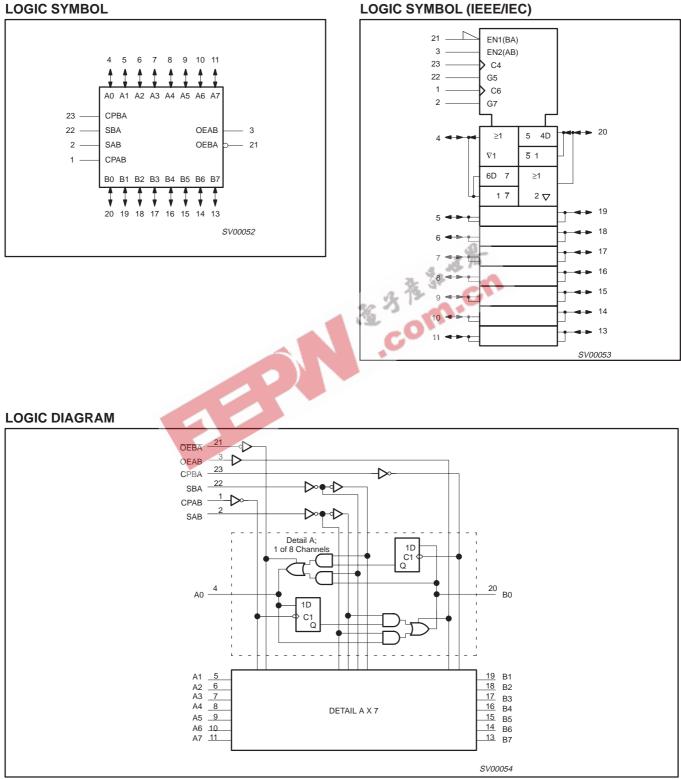


PIN DESCRIPTION

PIN NUMBER	SYMBOL	FUNCTION
1, 23	CPAB / CPBA	A to B clock input / B to A clock input
2, 22	SAB / SBA	A to B select input / B to A select input
3, 21	OEAB / OEBA	A to B Output Enable input (active-High) / B to A Output Enable input (active-Low)
4, 5, 6, 7, 8, 9, 10, 11	A0 – A7	Data inputs/outputs (A side)
20, 19, 18, 17, 16, 15, 14, 13	B0 – B7	Data inputs/outputs (B side)
12	GND	Ground (0V)
24	V _{CC}	Positive supply voltage

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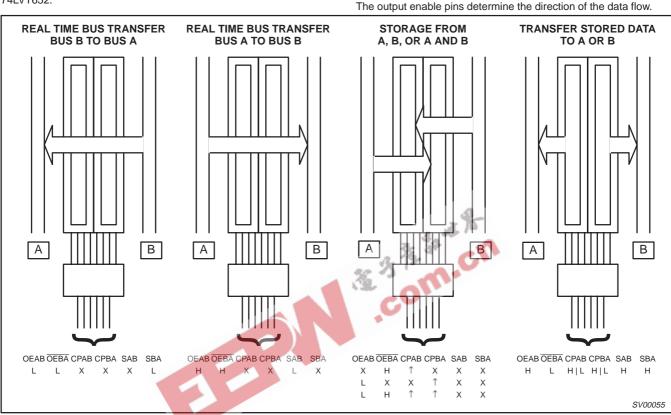




74LVT652

The following examples demonstrate the four fundamental bus-management functions that can be performed with the 74LVT652.

The select pins determine whether data is stored or transferred through the device in real time.



FUNCTION TABLE

INPUTS						DAT	A I/O	OPERATING MODE
OEAB	OEBA	CPAB	СРВА	SAB	SBA	An	Bn	OFERATING MODE
L	H H	H or L ↑	H or L ↑	X X	X X	Input	Input	Isolation Store A and B data
X H	H H	$\stackrel{\uparrow}{\leftarrow}$	H or L ↑	X **	X X	Input	Unspecified** Output*	Store A, Hold B Store A in both registers
L	X L	H or L ↑	$\stackrel{\uparrow}{\uparrow}$	X X	X **	Unspecified** Output*	Input	Hold A, Store B Store B in both registers
L	L L	X X	X H or L	X X	L H	Output	Input	Real time B data to A bus Stored B data to A bus
H H	H H	X H or L	X X	L H	X X	Input	Output	Real time A data to B bus Store A data to B bus
н	L	H or L	H or L	н	Н	Output	Output	Stored A data to B bus Stored B data to A bus

Η High voltage level =

Low voltage level L =

= Don't care

X ↑ Low-to-High clock transition =

The data output function may be enabled or disabled by various signals at the OEBA and OEAB inputs. Data input functions are always enabled, i.e., data at the bus pins will be stored on every Low-to-High transition of the clock.

** If both Select controls (SAB and SBA) are Low, then clocks can occur simultaneously. If either Select control is High, the clocks must be staggered in order to load both registers.

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ABSOLUTE MAXIMUM RATINGS^{1,2}

SYMBOL	PARAMETER	CONDITIONS	RATING	UNIT
V _{CC}	DC supply voltage		-0.5 to +4.6	V
I _{IK}	DC input diode current	V ₁ < 0	-50	mA
VI	DC input voltage ³		-0.5 to +7.0	V
I _{OK}	DC output diode current	V _O < 0	-50	mA
V _{OUT}	DC output voltage ³	Output in Off	-0.5 to +7.0	V
		Output in Low state	128	
IOUT	DC output current	Output in High state	-64	mA
T _{stg}	Storage temperature range		-65 to +150	°C

NOTES:

1. Stresses beyond those listed may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

The performance capability of a high-performance integrated circuit in conjunction with its thermal environment can create junction 2.

The performance department of a high performance integrated or out in conjunction temperature of this integrated circuit should not exceed 150°C.
 The input and output negative voltage ratings may be exceeded if the input and output clamp current ratings are observed.

RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER	LI	MITS	
STINDUL	PAKAMETER	MIN	MAX	
V _{CC}	DC supply voltage	2.7	3.6	V
VI	Input voltage	0	5.5	V
V _{IH}	High-level input voltage	2.0		V
VIL	Input voltage		0.8	V
I _{OH}	High-level output current		-32	mA
I _{OL}	Low-level output current		32	mA
	Low-level output current; current duty cycle \leq 50%; f \geq 1kHz		64	7
$\Delta t/\Delta v$	Input transition rise or fall rate; Outputs enabled		10	ns/V
T _{amb}	Operating free-air temperature range	-40	+85	°C

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				LIMITS			
SYMBOL	PARAMETER	TEST CONDITIONS	Temp =	Temp = -40°C to +85°C			
			MIN	TYP ¹	MAX		
V _{IK}	Input clamp voltage	V _{CC} = 2.7V; I _{IK} = -18mA		-0.9	-1.2	V	
		$V_{CC} = 2.7$ to 3.6V; $I_{OH} = -100\mu A$	V _{CC} -0.2	V _{CC} -0.1			
V _{OH}	High-level output voltage	V _{CC} = 2.7V; I _{OH} = -8mA	2.4	2.5		V	
		V _{CC} = 3.0V; I _{OH} = -32mA	2.0	2.2			
		V _{CC} = 2.7V; I _{OL} = 100μA		0.1	0.2		
		V _{CC} = 2.7V; I _{OL} = 24mA		0.3	0.5		
V _{OL}	Low-level output voltage	V _{CC} = 3.0V; I _{OL} = 16mA		0.25	0.4	V	
		V _{CC} = 3.0V; I _{OL} = 32mA		0.3	0.5		
		$V_{CC} = 3.0V; I_{OL} = 32mA$ $V_{CC} = 3.0V; I_{OL} = 64mA$	n	0.4	0.55		
V _{RST}	Power-up output low voltage ⁵	$V_{CC} = 3.6V; I_O = 1mA; V_I = GND \text{ or } V_{CC}$		0.13	0.55	V	
		$V_{CC} = 3.6V; V_I = V_{CC} \text{ or GND}$		±0.1	±1		
		$V_{CC} = 0 \text{ or } 3.6V; V_1 = 5.5V$	IS	1.0	10		
I _I	Input leakage current	$V_{CC} = 3.6V; V_1 = 5.5V$		1.0	20	μΑ	
		$V_{CC} = 3.6V; V_I = V_{CC}$ I/O Data pir	ns ⁴	0.1	1		
		$V_{CC} = 3.6V; V_{I} = 0$		-1	-5		
I _{OFF}	Output off current	$V_{CC} = 0V; V_1 \text{ or } V_0 = 0 \text{ to } 4.5V$		1	±100	μΑ	
		$V_{CC} = 3V; V_{I} = 0.8V$	75	150			
I _{HOLD}	Bus Hold current A inputs ⁶	$V_{CC} = 3V; V_I = 2.0V$	-75	-150		μA	
		$V_{CC} = 0V \text{ to } 3.6V; V_{CC} = 3.6V$	±500			I	
I_{EX}	Current into an output in the High state when $V_O > V_{CC}$	$V_{O} = 5.5V; V_{CC} = 3.0V$		60	125	μA	
I _{PU/PD}	Power up/down 3-State output current ³	$V_{CC} \leq$ 1.2V; V_O = 0.5V to $V_{CC};$ V_I = GND or $V_{CC};$ OE/OE = Don't care		15	±100	μΑ	
I _{CCH}		V_{CC} = 3.6V; Outputs High, V_I = GND or V_{CC} , I_O = 0		0.13	0.19		
I _{CCL}	Quiescent supply current	V_{CC} = 3.6V; Outputs Low, V_I = GND or V_{CC} , I_O = 0		3	12	mA	
I _{CCZ}	1	V_{CC} = 3.6V; Outputs Disabled; V_{I} = GND or $V_{CC,\ I_{O}}$ =	0	0.13	0.19		
ΔI _{CC}	Additional supply current per input pin ²	V_{CC} = 3V to 3.6V; One input at V_{CC} -0.6V, Other inputs at V_{CC} or GND		0.1	0.2	mA	

DC ELECTRICAL CHARACTERISTICS

NOTES:

All typical values are at V_{CC} = 3.3V and T_{amb} = 25°C.
 This is the increase in supply current for each input at the specified voltage level other than V_{CC} or GND
 This parameter is valid for any V_{CC} between 0V and 1.2V with a transition time of up to 10msec. From V_{CC} = 1.2V to V_{CC} = 3.3V ± 0.3V a transition time of 100µsec is permitted. This parameter is valid for T_{amb} = 25°C only.
 Unused pins at V_{CC} or GND.
 For wolid text results, data must not be leaded into the flip flops (or latebas) after applying power.

5. For valid test results, data must not be loaded into the flip-flops (or latches) after applying power.

6. This is the bus hold overdrive current required to force the input to the opposite logic state.

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AC CHARACTERISTICS

GND = 0V, $t_R = t_F$ = 2.5ns, C_L = 50pF, R_L = 500 Ω ; T_{amb} = -40°C to +85°C.

				LIMITS					
SYMBOL	PARAMETER	WAVEFORM	Vc	$_{ m C}$ = 3.3V \pm 0	.3V	V _{CC} = 2.7V	UNIT		
			MIN	TYP ¹	MAX	MAX	1		
f _{MAX}	Maximum clock frequency	1	150	180			MHz		
t _{PLH} t _{PHL}	Propagation delay CPAB to Bn or CPBA to An	1	1.8 2.0	3.7 3.7	6.0 5.7	6.9 6.4	ns		
t _{PLH} t _{PHL}	Propagation delay An to Bn or Bn to An	2	1.2 1.0	2.8 2.6	4.7 4.6	5.5 5.3	ns		
t _{PLH} t _{PHL}	Propagation delay SAB to Bn or SBA to An	3	1.4 1.4	3.7 4.0	6.4 6.2	7.6 6.8	ns		
t _{PZH} t _{PZL}	Output enable time OEBA to An	5 6	1.0 1.0	2.9 3.0	5.8 6.0	7.2 7.3	ns		
t _{PHZ} t _{PLZ}	Output disable time OEBA to An	5 6	2.2 1.8	3.9 3.2	6.5 5.8	6.9 5.9	ns		
t _{PZH} t _{PZL}	Output enable time OEAB to Bn	5 6	1.0 1.2	3.3 3.4	6.5 6.3	7.5 7.1	ns		
t _{PHZ} t _{PLZ}	Output disable time OEAB to Bn	5	1.7 1.5	4.5 3.8	7.2 5.8	8.1 6.3	ns		
NOTE: 1. All typical	values are at V _{CC} = 3.3V and T _{amb} = 2	25°C.	COL						

AC SETUP REQUIREMENTS

GND = 0V, t_R = 2.5ns, t_F = 2.5ns, C_L = 50pF, R_L = 500 Ω , T_{amb} =40 °C to 85 °C

			LIMITS					
SYMBOL	PARAMETER	WAVEFORM	٢	「 _{amb} = +25° V _{CC} = +5.0∖	C /	+8	= -40 to 5°C .0V ±0.5V	UNIT
			Min	Тур	Max	Min	Max	
t _s (H) t _s (L)	Setup time ¹ An to CPAB, Bn to CPBA	4	1.5 2.2	0.9 1.1		1.6 2.5		ns
t _h (H) t _h (L)	Hold time ¹ An to CPAB, Bn to CPBA	4	0 0	-1.0 -1.0		0.0 0.0		ns
t _w (H) t _w (L)	Pulse width, High or Low CPAB or CPBA	1	3.3 3.3	1.0 2.0		3.3 3.3		ns

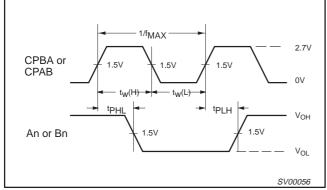
NOTE:

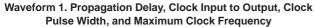
1. This data sheet limit may vary among suppliers.

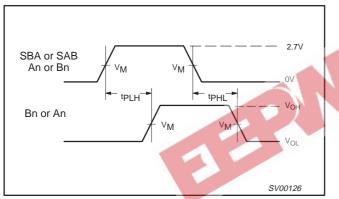
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AC WAVEFORMS

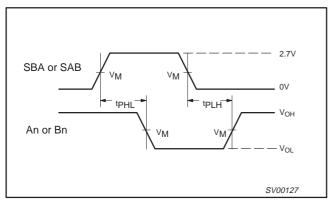
 V_{M} = 1.5V, V_{IN} = GND to 2.7V



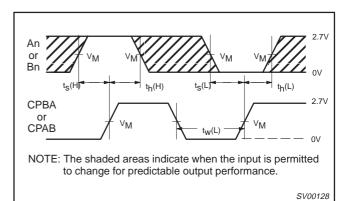




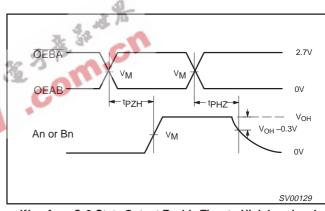
Waveform 2. Propagation Delay, An to Bn or Bn to An, SAB to Bn or SBA to An



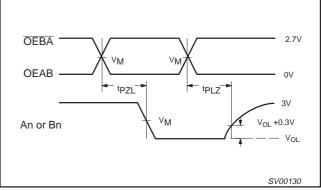
Waveform 3. Propagation Delay, SBA to An or SAB to Bn



Waveform 4. Data Setup and Hold Times



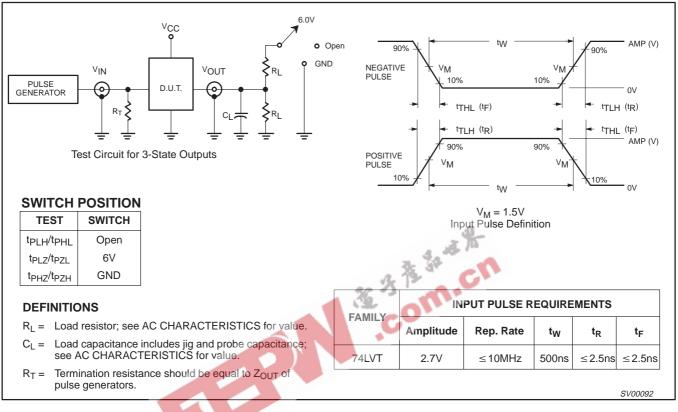
Waveform 5. 3-State Output Enable Time to High Level and Output Disable Time from High Level



Waveform 6. 3-State Output Enable Time to Low Level and Output Disable Time from Low Level

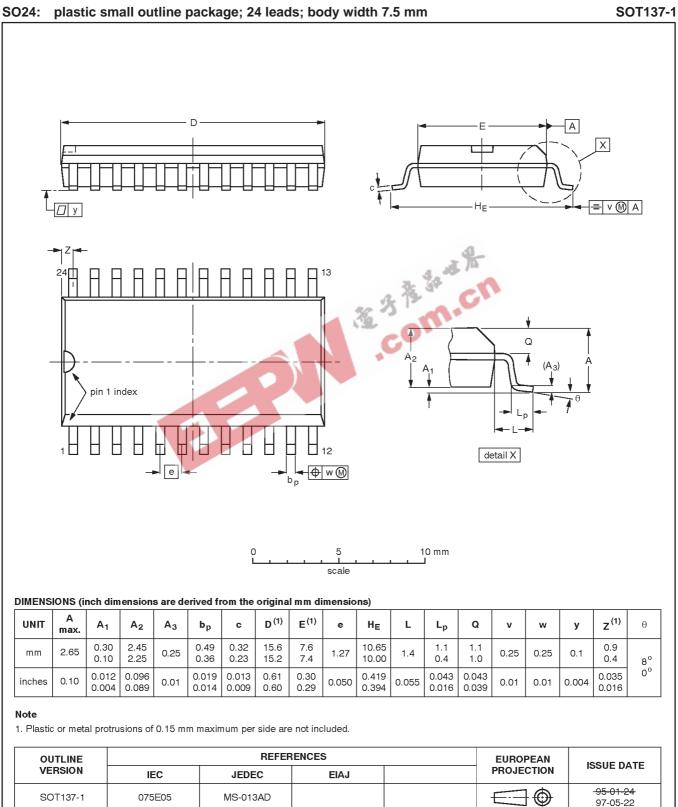
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TEST CIRCUIT AND WAVEFORM



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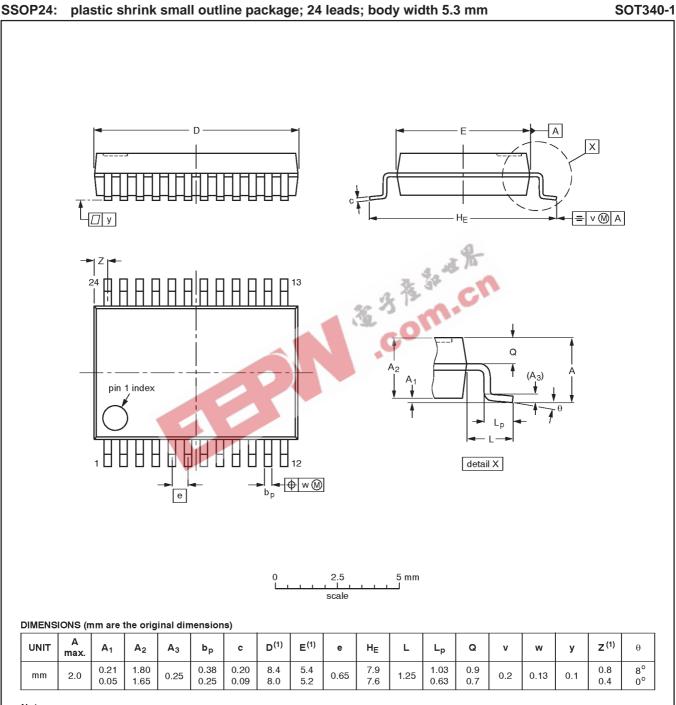
3.3V Octal transceiver/register, non-inverting (3-State)



SO24:

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3.3V Octal transceiver/register, non-inverting (3-State)



SSOP24: plastic shrink small outline package; 24 leads; body width 5.3 mm

Note

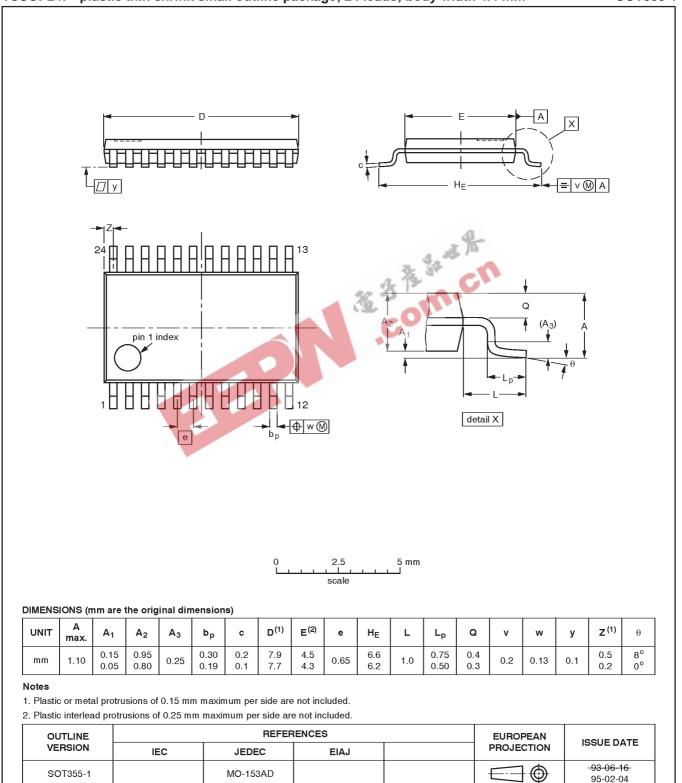
1. Plastic or metal protrusions of 0.20 mm maximum per side are not included.

OUTLINE		REFER	REFERENCES		EUROPEAN	
VERSION	IEC	JEDEC	EIAJ		PROJECTION	ISSUE DATE
SOT340-1		MO-150AG				-93-09-08 95-02-04
						95-02-04

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3.3V Octal transceiver/register, non-inverting (3-State)





Product specification

74LVT652

NOTES



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Data sheet status

Data sheet status	Product status	Definition ^[1]
Objective specification	Development	This data sheet contains the design target or goal specifications for product development. Specification may change in any manner without notice.
Preliminary specification	Qualification	This data sheet contains preliminary data, and supplementary data will be published at a later date. Philips Semiconductors reserves the right to make chages at any time without notice in order to improve design and supply the best possible product.
Product specification	Production	This data sheet contains final specifications. Philips Semiconductors reserves the right to make changes at any time without notice in order to improve design and supply the best possible product.

[1] Please consult the most recently issued datasheet before initiating or completing a design.

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Limiting values definition — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

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print code Document order number:

PHILIPS

Date of release: 05-96 9397-750-03545

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